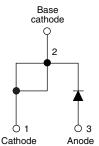
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**Vishay Semiconductors** 

# Fast Soft Recovery Rectifier Diode, 10 A





PRODUCT SUMMARY				
Package	TO-220FP			
I <sub>F(AV)</sub>	10 A			
V <sub>R</sub>	1000 V, 1200 V			
V <sub>F</sub> at I <sub>F</sub>	1.33 V			
I <sub>FSM</sub>	140 A			
t <sub>rr</sub>	80 ns			
T <sub>J</sub> max.	150 °C			
Diode variation	Single die			
Snap factor	0.6			

### **FEATURES**

- 150 °C max. operation junction temperature
- Designed and qualified according to JEDEC-JESD47
- Fully isolated package (V<sub>INS</sub> = 2500 V<sub>RMS</sub>)
- UL E78996 approved

### **APPLICATIONS**

These devices are intended for use in output rectification and freewheeling in inverters, choppers and converters as well as in input rectification where severe restrictions on conducted EMI should be met.

### DESCRIPTION

The VS-10ETF1..FP... fast soft recovery rectifier series has been optimized for combined short reverse recovery time and low forward voltage drop.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	CHARACTERISTICS VALUES				
V <sub>RRM</sub>		1000 to 1200	V			
I <sub>F(AV)</sub>	Sinusoidal waveform	10	٨			
I <sub>FSM</sub>		140	– A			
t <sub>rr</sub>	1 A, 100 A/μs	80	ns			
V <sub>F</sub>	10 A, T <sub>J</sub> = 25 °C	1.33	V			
TJ		- 40 to 150	°C			

VOLTAGE RATINGS					
PART NUMBER	V <sub>RRM</sub> , MAXIMUM PEAK REVERSE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I <sub>RRM</sub> AT 150 °C mA		
VS-10ETF10FPPbF, VS-10ETF10FP-M3	1000	1100	4		
VS-10ETF12FPPbF, VS-10ETF12FP-M3	1200	1300	4		

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum average forward current	I <sub>F(AV)</sub>	$T_{C} = 95 \text{ °C}$ , 180° conduction half sine wave	10			
Maximum peak one cycle	I	10 ms sine pulse, rated V <sub>RRM</sub> applied	115	А		
non-repetitive surge current	I <sub>FSM</sub>	10 ms sine pulse, no voltage reapplied	140			
Maximum I <sup>2</sup> t for fusing	l <sup>2</sup> t	10 ms sine pulse, rated V <sub>RRM</sub> applied	66	A <sup>2</sup> s		
		10 ms sine pulse, no voltage reapplied	94	A-2		
Maximum I <sup>2</sup> $\sqrt{t}$ for fusing	l²√t	t = 0.1 to 10 ms, no voltage reapplied	940	A²√s		

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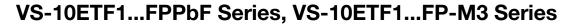
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Material categorization: For definitions of compliance please see www.vishay.com/doc?99912





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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop	V <sub>FM</sub>	10 A, T <sub>J</sub> = 25 °C		1.33	V
Forward slope resistance	r <sub>t</sub>	T, = 150 °C		22.9	mΩ
Threshold voltage	V <sub>F(TO)</sub>	1j = 150 C		0.96	V
		T <sub>J</sub> = 25 °C		0.1	
Maximum reverse leakage current	I <sub>RM</sub>	T <sub>J</sub> = 150 °C	V <sub>R</sub> = Rated V <sub>RRM</sub>	4	mA

RECOVERY CHARACTERISTICS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Reverse recovery time	t <sub>rr</sub>	l <sub>F</sub> at 10 Apk 25 A/μs 25 ℃	310	ns	I <sub>FM</sub> t.	
Reverse recovery current	I <sub>rr</sub>		4.7	А		
Reverse recovery charge	Q <sub>rr</sub>		1.05	μC	$\frac{\text{dir}}{\text{dt}}$	
Snap factor	S		0.6		I IRM(REC)	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL TEST CONDITIONS		VALUES	UNITS	
Maximum junction and sto temperature range	orage	T <sub>J</sub> , T <sub>Stg</sub>		- 40 to 150	°C	
Maximum thermal resistance junction to case		R <sub>thJC</sub>	DC operation	2.5		
Maximum thermal resistance junction to ambient		R <sub>thJA</sub>		62	°C/W	
Typical thermal resistance case to heatsink	9,	R <sub>thCS</sub>	Mounting surface, smooth and greased	0.5		
Approvimeto weight				2	g	
Approximate weight				0.07	oz.	
Mounting torque	minimum			6 (5)	kgf · cm	
Mounting torque maximu	maximum			12 (10)	(lbf · in)	
Marking device			Case style TO-220 FULL-PAK	10ETF10FP 10ETF12FP		

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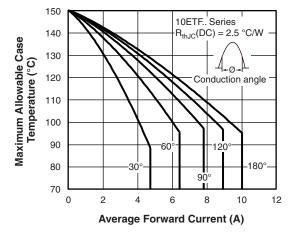


Fig. 1 - Current Rating Characteristics

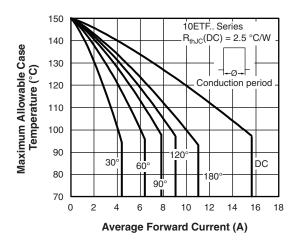


Fig. 2 - Current Rating Characteristics

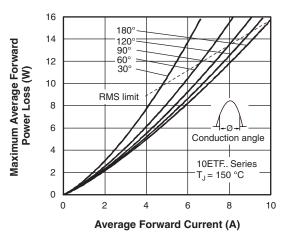


Fig. 3 - Forward Power Loss Characteristics

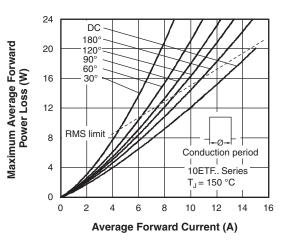


Fig. 4 - Forward Power Loss Characteristics

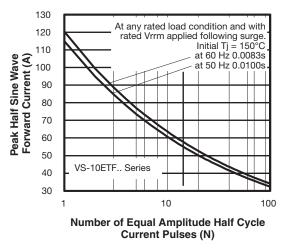


Fig. 5 - Maximum Non-Repetitive Surge Current

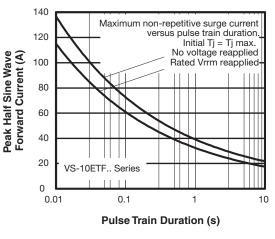


Fig. 6 - Maximum Non-Repetitive Surge Current

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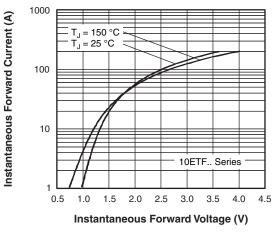


Fig. 7 - Forward Voltage Drop Characteristics

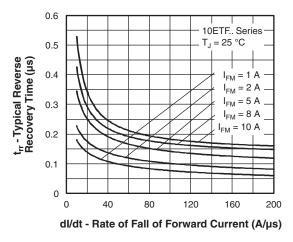


Fig. 8 - Recovery Time Characteristics, T<sub>J</sub> = 25 °C

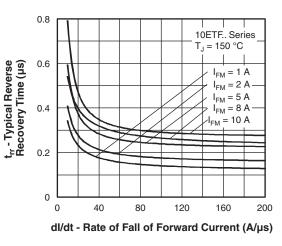
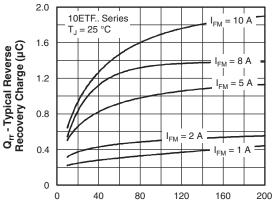


Fig. 9 - Recovery Time Characteristics,  $T_J$  = 150  $^\circ\text{C}$ 



dl/dt - Rate of Fall of Forward Current (A/µs)

Fig. 10 - Recovery Charge Characteristics, T<sub>J</sub> = 25 °C

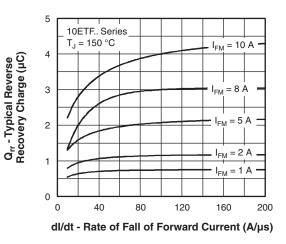
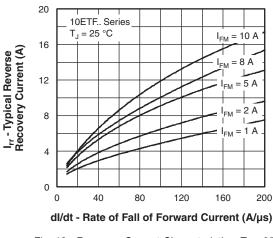


Fig. 11 - Recovery Charge Characteristics, T<sub>J</sub> = 150 °C



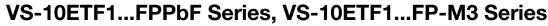


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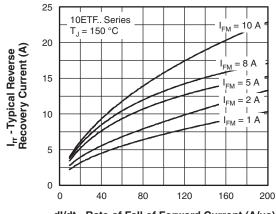
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dl/dt - Rate of Fall of Forward Current (A/µs)

Fig. 13 - Recovery Current Characteristics, T<sub>J</sub> = 150 °C

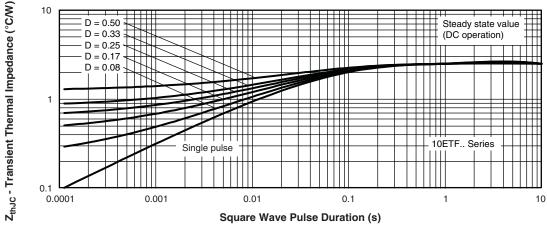


Fig. 14 - Thermal Impedance Z<sub>thJC</sub> Characteristics

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### **ORDERING INFORMATION TABLE**

Device code	VS-	10	Е	т	F	12	FP	PbF
		2	3	4	5	6	(7)	8
	<ol> <li>Vishay Semiconductors product</li> <li>Current rating (10 = 10 A)</li> <li>Circuit configuration: E = Single diode</li> <li>Package: T = TO-220</li> </ol>							
	5 - 6 - 7 - 8 -	F = Vol FUI Env	tage coo _L-PAK ⁄ironmer	ft recove le x 100 ntal digit ad (Pb)-1	= V <sub>RRM</sub>	1	- 04 = 4 06 = 6	

• -M3 = Halogen-free, RoHS compliant and terminations lead (Pb)-free

ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-10ETF10FPPbF	50	1000	Antistatic plastic tubes			
VS-10ETF10FP-M3	50	1000	Antistatic plastic tubes			
VS-10ETF12FPPbF	50	1000	Antistatic plastic tubes			
VS-10ETF12FP-M3	50	1000	Antistatic plastic tubes			

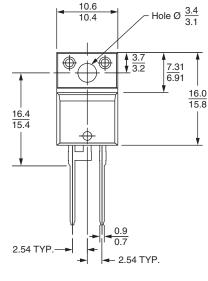
LINKS TO RELATED DOCUMENTS					
Dimensions		www.vishay.com/doc?95005			
Part marking information	TO-220 FP PbF	www.vishay.com/doc?95009			
Part marking information	TO-220 FP -M3	www.vishay.com/doc?95440			



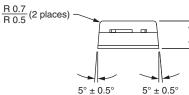
## **Outline Dimensions**

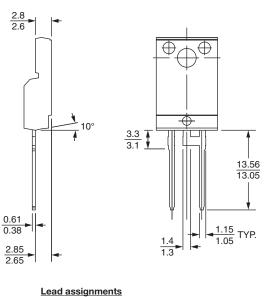
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### **DIMENSIONS** in millimeters



 $\frac{4.8}{4.6}$ 





<u>Lead assignments</u> <u>Diodes</u> 1 + 2 - Cathode 3 - Anode

Conforms to JEDEC outline TO-220 FULL-PAK



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